

# SN65LBC172, SN75LBC172 QUADRUPLE LOW-POWER DIFFERENTIAL LINE DRIVER

SLLS163E – JULY 1993 – REVISED APRIL 2006

- Meets or Exceeds EIA Standard RS-485
- Designed for High-Speed Multipoint Transmission on Long Bus Lines in Noisy Environments
- Support Data Rates up to and Exceeding Ten Million Transfers Per Second
- Common-Mode Output Voltage Range of –7 V to 12 V
- Positive- and Negative-Current Limiting
- Low Power Consumption . . . 1.5 mA Max (Output Disabled)
- Functionally Interchangeable With SN75172

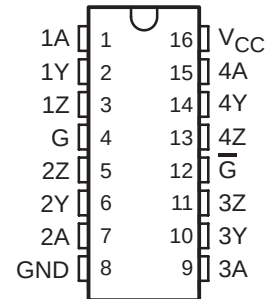
## description

The SN65LBC172 and SN75LBC172 are monolithic quadruple differential line drivers with 3-state outputs. Both devices are designed to meet the requirements of EIA Standard RS-485. These devices are optimized for balanced multipoint bus transmission at data rates up to and exceeding 10 million bits per second. Each driver features wide positive and negative common-mode output voltage ranges, current limiting, and thermal-shutdown circuitry making it suitable for party-line applications in noisy environments. Both devices are designed using LinBiCMOS™, facilitating ultra-low power consumption and inherent robustness.

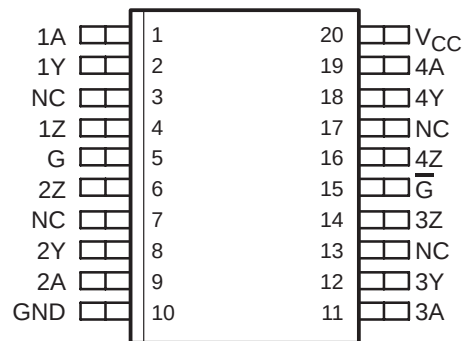
Both the SN65LBC172 and SN75LBC172 provide positive- and negative-current limiting and thermal shutdown for protection from line fault conditions on the transmission bus line. These devices offer optimum performance when used with the SN75LBC173 or SN75LBC175 quadruple line receivers. The SN65LBC172 and SN75LBC172 are available in the 16-pin DIP package (N) and the 20-pin wide-body small-outline inline-circuit (SOIC) package (DW).

The SN75LBC172 is characterized for operation over the commercial temperature range of 0°C to 70°C. The SN65LBC172 is characterized over the industrial temperature range of –40°C to 85°C.

**N PACKAGE  
(TOP VIEW)**



**DW PACKAGE  
(TOP VIEW)**



NC – No internal connection

**FUNCTION TABLE  
(each driver)**

| INPUT<br>A | ENABLES |       | OUTPUTS |   |
|------------|---------|-------|---------|---|
|            | G       | G-bar | Y       | Z |
| H          | H       | X     | H       | L |
| L          | H       | X     | L       | H |
| H          | X       | L     | H       | L |
| L          | X       | L     | L       | H |
| X          | L       | H     | Z       | Z |

H = high level, L = low level,  
X = irrelevant, Z = high impedance (off)



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



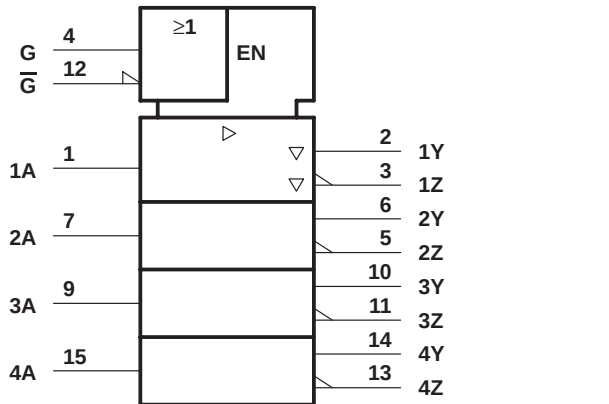
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# SN65LBC172, SN75LBC172 QUADRUPLE LOW-POWER DIFFERENTIAL LINE DRIVER

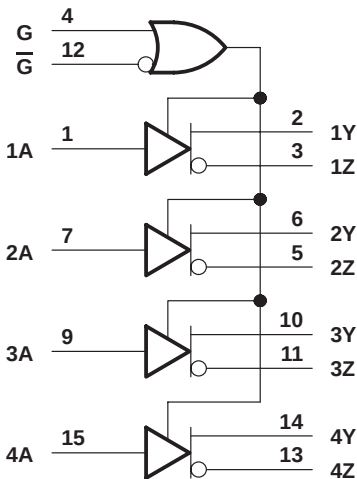
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logic symbol†

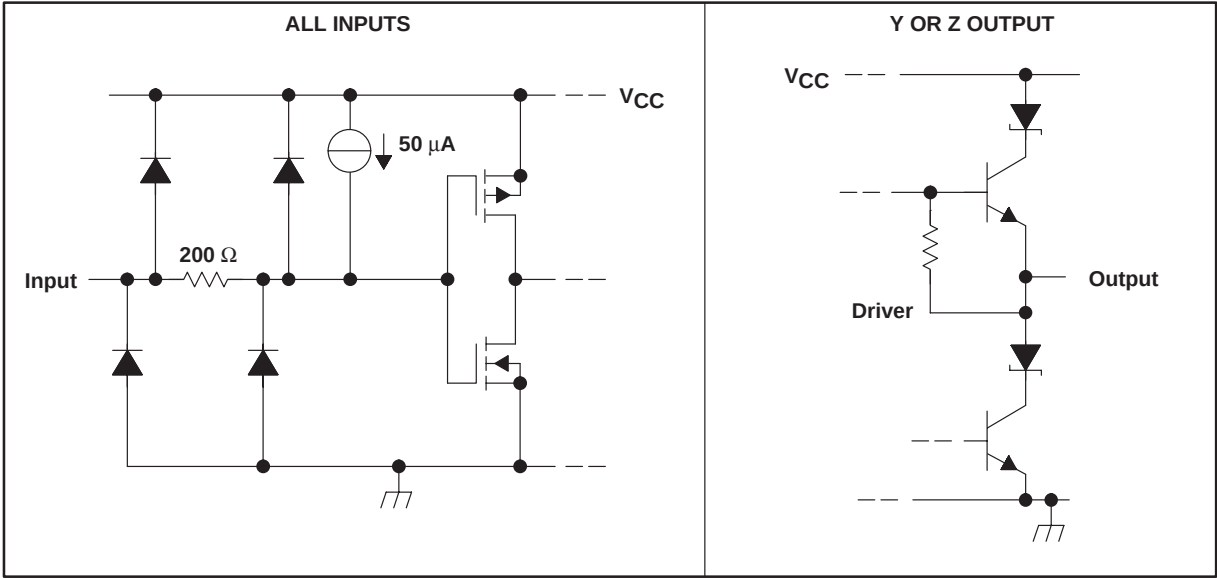


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the N package.

logic diagram (positive logic)



schematic diagrams of inputs and outputs



# SN65LBC172, SN75LBC172 QUADRUPLE LOW-POWER DIFFERENTIAL LINE DRIVER

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## absolute maximum ratings<sup>†</sup>

|                                                              |                                 |
|--------------------------------------------------------------|---------------------------------|
| Supply voltage range, $V_{CC}$ (see Note 1)                  | –0.3 V to 7 V                   |
| Output voltage range, $V_O$                                  | –10 V to 15 V                   |
| Voltage range at A, $\overline{G}$ , G                       | –0.3 V to $V_{CC} + 0.5$ V      |
| Continuous power dissipation                                 | Internally limited <sup>‡</sup> |
| Storage temperature range, $T_{stg}$                         | –65°C to 150°C                  |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | 260°C                           |

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>‡</sup> The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature.

NOTE 1: All voltage values are with respect to GND.

## recommended operating conditions

|                                                                |            | MIN                          | NOM | MAX  | UNIT |
|----------------------------------------------------------------|------------|------------------------------|-----|------|------|
| Supply voltage, $V_{CC}$                                       |            | 4.75                         | 5   | 5.25 | V    |
| High-level input voltage, $V_{IH}$                             |            | 2                            |     |      | V    |
| Low-level input voltage, $V_{IL}$                              |            |                              |     | 0.8  | V    |
| Voltage at any bus terminal (separately or common mode), $V_O$ | Y or Z     |                              |     | 12   | V    |
|                                                                |            |                              |     | –7   | V    |
| High-level output current, $I_{OH}$                            | Y or Z     |                              |     | –60  | mA   |
| Low-level output current, $I_{OL}$                             | Y or Z     |                              |     | 60   | mA   |
| Continuous total power dissipation                             |            | See Dissipation Rating Table |     |      |      |
| Junction temperature, $T_J$                                    |            |                              |     | 140  | °C   |
| Operating free-air temperature, $T_A$                          | SN65LBC172 | –40                          |     | 85   | °C   |
|                                                                | SN75LBC172 | 0                            |     | 70   | °C   |

DISSIPATION RATING TABLE

| PACKAGE | THERMAL MODEL     | $T_A < 25^\circ\text{C}$<br>POWER RATING | DERATING FACTOR<br>ABOVE $T_A = 25^\circ\text{C}$ | $T_A = 70^\circ\text{C}$<br>POWER RATING | $T_A = 85^\circ\text{C}$<br>POWER RATING |
|---------|-------------------|------------------------------------------|---------------------------------------------------|------------------------------------------|------------------------------------------|
| DW      | Low $K^\dagger$   | 1094 mW                                  | 10.4 mW/°C                                        | 625 mW                                   | 469 mW                                   |
|         | High $K^\ddagger$ | 1669 mW                                  | 15.9 mW/°C                                        | 954 mW                                   | 715 mW                                   |
| N       |                   | 1150 mW                                  | 9.2 mW/°C                                         | 736 mW                                   | 598 mW                                   |

<sup>†</sup> In accordance with the low effective thermal conductivity metric definitions of EIA/JESD 51–3.

<sup>‡</sup> In accordance with the high effective thermal conductivity metric definitions of EIA/JESD 51–7.

# SN65LBC172, SN75LBC172

## QUADRUPLE LOW-POWER DIFFERENTIAL LINE DRIVER

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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

| PARAMETER         |                                                                | TEST CONDITIONS                                         |                  | MIN     | TYP <sup>†</sup> | MAX  | UNIT |
|-------------------|----------------------------------------------------------------|---------------------------------------------------------|------------------|---------|------------------|------|------|
| V <sub>IK</sub>   | Input clamp voltage                                            | I <sub>I</sub> = −18 mA                                 |                  |         |                  | −1.5 | V    |
| V <sub>OD</sub>   | Differential output voltage <sup>‡</sup>                       | R <sub>L</sub> = 54 Ω,<br>See Figure 1                  | SN65LBC172       | 1.1     | 1.8              | 5    | V    |
|                   |                                                                |                                                         | SN75LBC172       | 1.5     | 1.8              | 5    |      |
|                   |                                                                | R <sub>L</sub> = 60 Ω,<br>See Figure 2                  | SN65LBC172       | 1.1     | 1.7              | 5    |      |
|                   |                                                                |                                                         | SN75LBC172       | 1.5     | 1.7              | 5    |      |
| Δ V <sub>OD</sub> | Change in magnitude of common-mode output voltage <sup>§</sup> | R <sub>L</sub> = 54 Ω,      See Figure 1                |                  | ±0.2    |                  |      | V    |
| V <sub>OC</sub>   | Common-mode output voltage                                     |                                                         |                  | 3<br>−1 |                  |      | V    |
| Δ V <sub>OC</sub> | Change in magnitude of common-mode output voltage <sup>§</sup> |                                                         |                  | ±0.2    |                  |      | V    |
| I <sub>O</sub>    | Output current with power off                                  | V <sub>CC</sub> = 0,      V <sub>O</sub> = −7 V to 12 V |                  | ±100    |                  |      | μA   |
| I <sub>OZ</sub>   | High-impedance-state output current                            | V <sub>O</sub> = −7 V to 12 V                           |                  | ±100    |                  |      | μA   |
| I <sub>IH</sub>   | High-level input current                                       | V <sub>I</sub> = 2.4 V                                  |                  | −100    |                  |      | μA   |
| I <sub>IL</sub>   | Low-level input current                                        | V <sub>I</sub> = 0.4 V                                  |                  | −100    |                  |      | μA   |
| I <sub>OS</sub>   | Short-circuit output current                                   | V <sub>O</sub> = −7 V to 12 V                           |                  | ±250    |                  |      | mA   |
| I <sub>CC</sub>   | Supply current (all drivers)                                   | No load                                                 | Outputs enabled  | 7       |                  |      | mA   |
|                   |                                                                |                                                         | Outputs disabled | 1.5     |                  |      |      |

<sup>†</sup> All typical values are at V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C.

<sup>‡</sup> The minimum V<sub>OD</sub> specification does not fully comply with EIA-485 at operating temperatures below 0°C. The lower output signal should be used to determine the maximum signal-transmission distance.

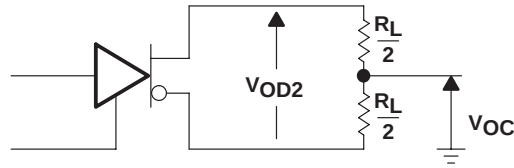
<sup>§</sup> Δ|V<sub>OD</sub>| and Δ|V<sub>OC</sub>| are the changes in magnitude of V<sub>OD</sub> and V<sub>OC</sub>, respectively, that occur when the input changes from a high level to a low level.

### switching characteristics, V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C

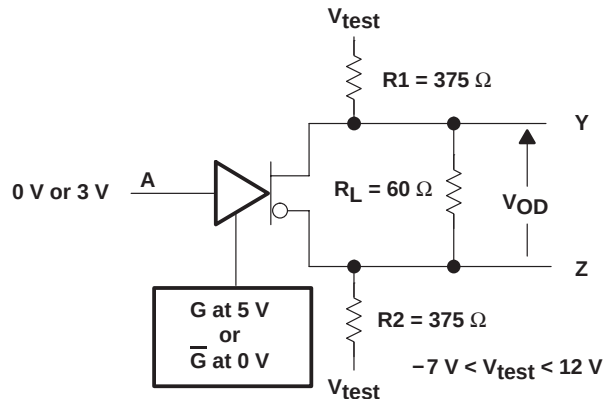
| PARAMETER                                              | TEST CONDITIONS                      | MIN | TYP | MAX | UNIT |
|--------------------------------------------------------|--------------------------------------|-----|-----|-----|------|
| t <sub>d(OD)</sub> Differential output delay time      | R <sub>L</sub> = 54 Ω, See Figure 3  | 2   | 11  | 20  | ns   |
| t <sub>t(OD)</sub> Differential output transition time |                                      | 10  | 15  | 25  |      |
| t <sub>pZH</sub> Output enable time to high level      | R <sub>L</sub> = 110 Ω, See Figure 4 |     | 20  | 30  | ns   |
| t <sub>pZL</sub> Output enable time to low level       | R <sub>L</sub> = 110 Ω, See Figure 5 |     | 21  | 30  | ns   |
| t <sub>PHZ</sub> Output disable time from high level   | R <sub>L</sub> = 110 Ω, See Figure 4 |     | 48  | 70  | ns   |
| t <sub>PLZ</sub> Output disable time from low level    | R <sub>L</sub> = 110 Ω, See Figure 5 |     | 21  | 30  | ns   |



### PARAMETER MEASUREMENT INFORMATION

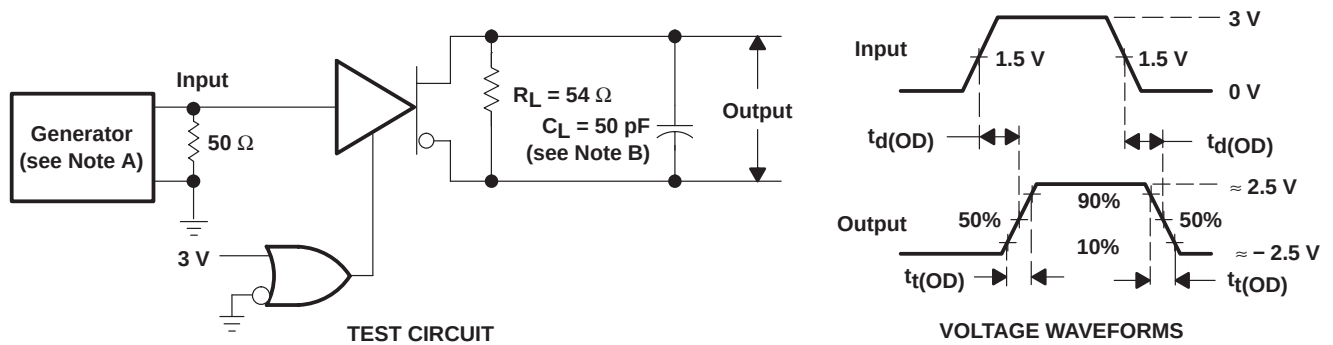


**Figure 1. Differential and Common-Mode Output Voltages**



NOTES: A. The input pulse is supplied by a generator having the following characteristics:  $PRR \leq 1$  MHz, duty cycle = 50%,  $t_r \leq 5$  ns,  $t_f \leq 5$  ns,  $Z_O = 50 \Omega$ .  
 B.  $C_L$  includes probe and stray capacitance.

**Figure 2. Driver  $V_{OD}$  Test Circuit**



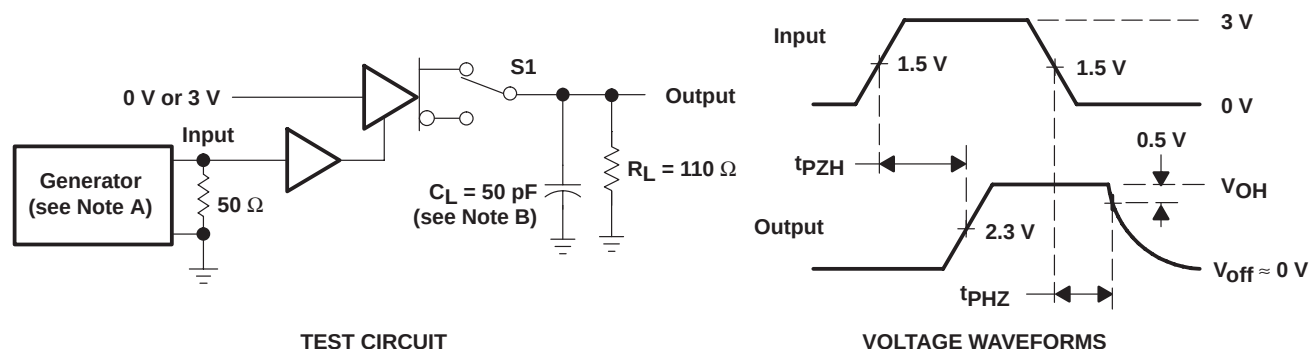
NOTES: A. The input pulse is supplied by a generator having the following characteristics:  $PRR \leq 1$  MHz, duty cycle = 50%,  $t_r \leq 5$  ns,  $t_f \leq 5$  ns,  $Z_O = 50 \Omega$ .  
 B.  $C_L$  includes probe and stray capacitance.

**Figure 3. Driver Differential-Output Test Circuit and Delay and Transition-Time Waveforms**

# SN65LBC172, SN75LBC172 QUADRUPLE LOW-POWER DIFFERENTIAL LINE DRIVER

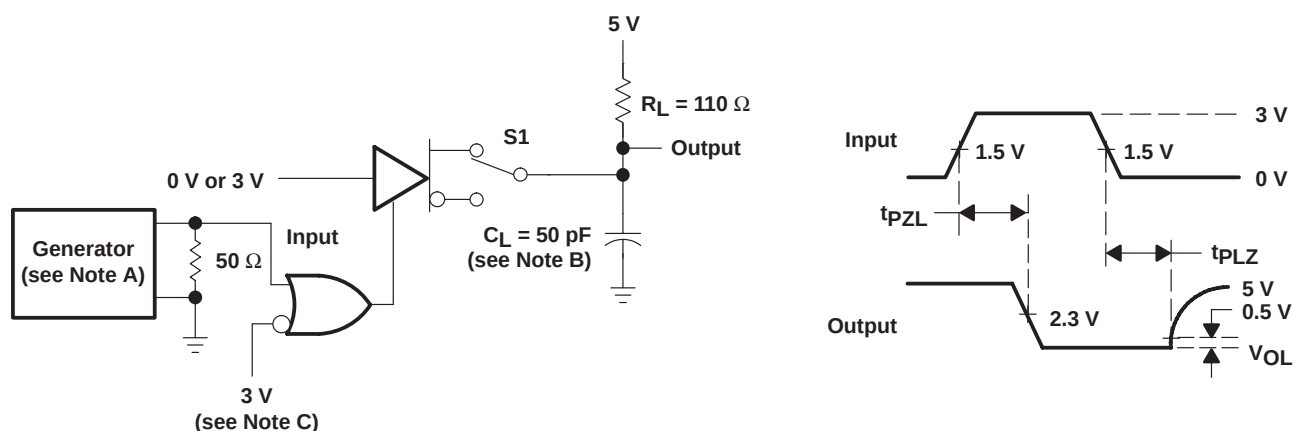
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## PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics:  $PRR \leq 1 \text{ MHz}$ , duty cycle = 50%,  $t_r \leq 5 \text{ ns}$ ,  $t_f \leq 5 \text{ ns}$ ,  $Z_O = 50 \Omega$ .  
B.  $C_L$  includes probe and stray capacitance.

Figure 4.  $t_{pZH}$  and  $t_{pHZ}$  Test Circuit and Voltage Waveforms



NOTES: A. The input pulse is supplied by a generator having the following characteristics:  $PRR \leq 1 \text{ MHz}$ , duty cycle = 50%,  $t_r \leq 5 \text{ ns}$ ,  $t_f \leq 5 \text{ ns}$ ,  $Z_O = 50 \Omega$ .  
B.  $C_L$  includes probe and stray capacitance.  
C. To test the active-low enable  $\overline{G}$ , ground G and apply an inverted waveform to  $\overline{G}$ .

Figure 5.  $t_{pZL}$  and  $t_{pLZ}$  Test Circuit and Waveforms

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## TYPICAL CHARACTERISTICS

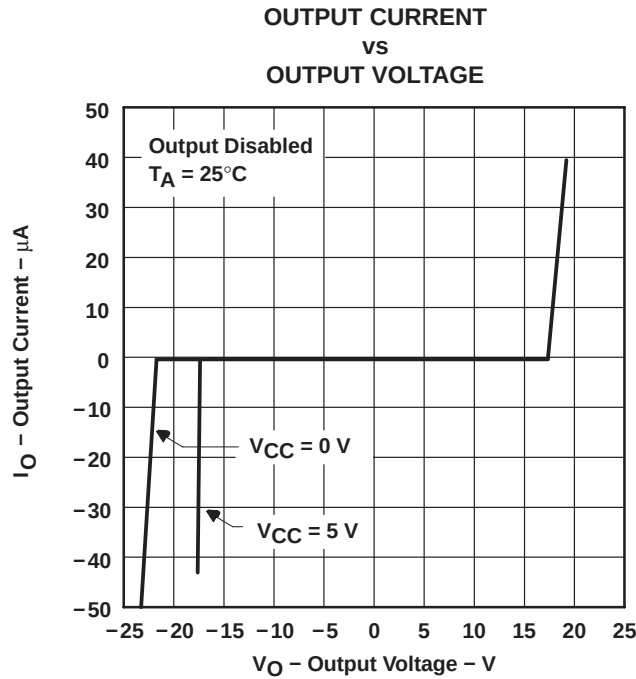


Figure 6

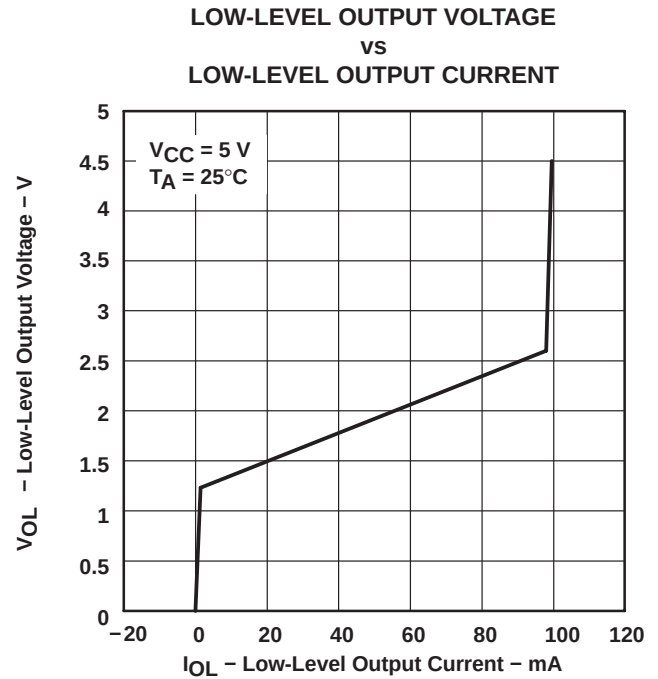


Figure 7

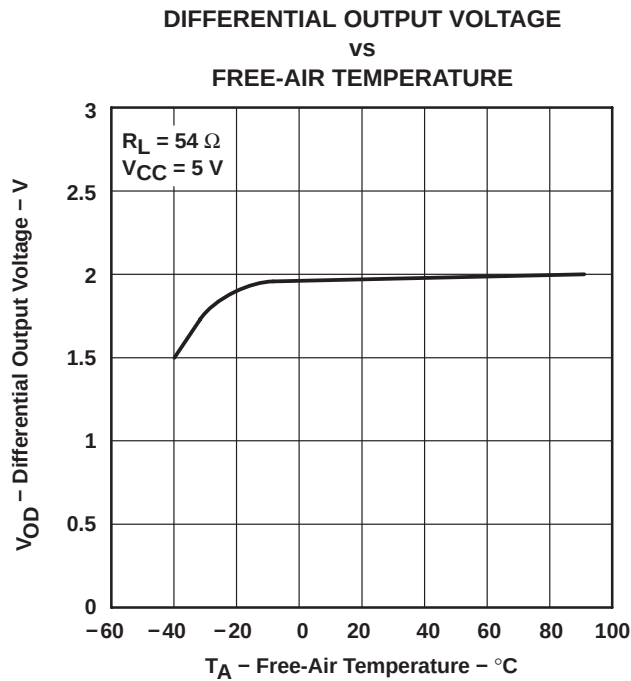


Figure 8

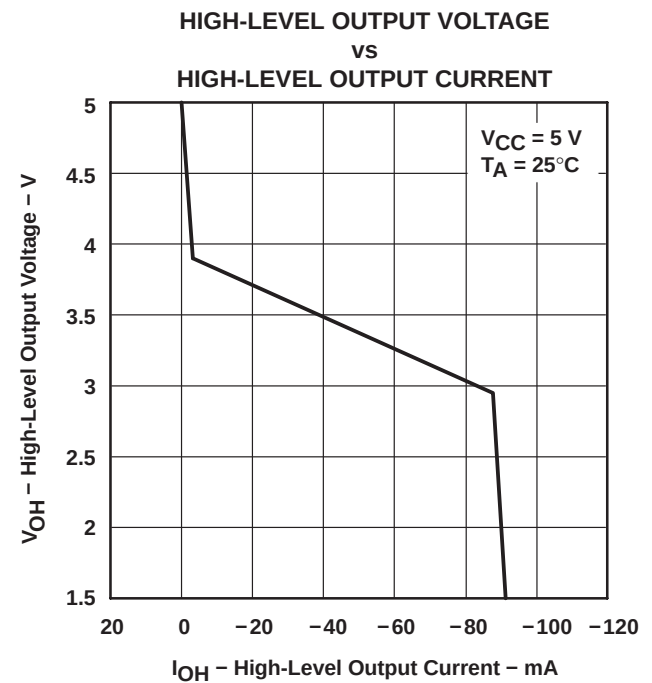
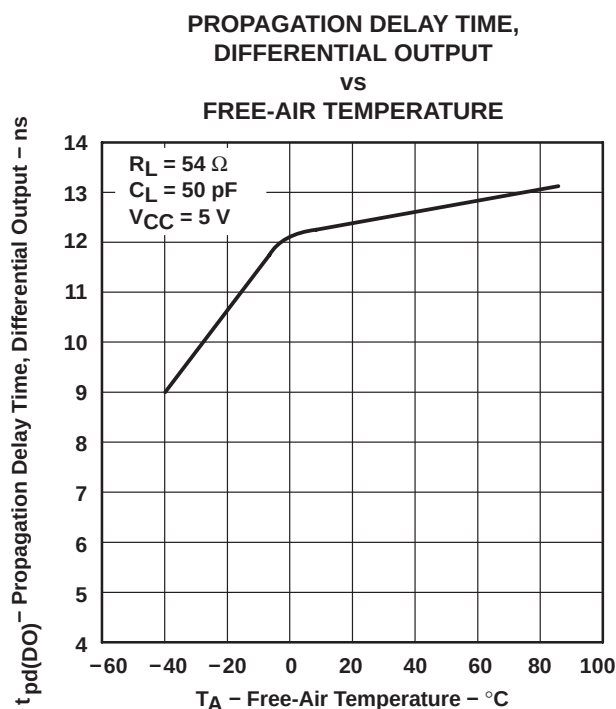
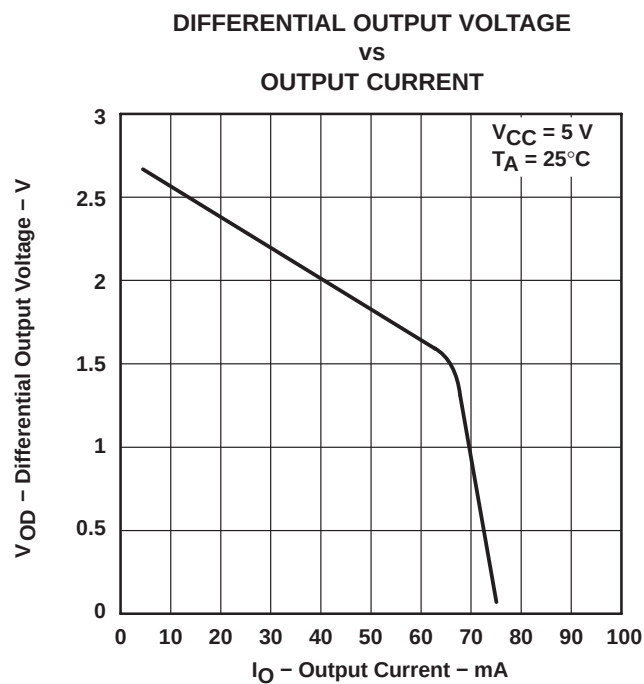


Figure 9

# SN65LBC172, SN75LBC172 QUADRUPLE LOW-POWER DIFFERENTIAL LINE DRIVER

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## TYPICAL CHARACTERISTICS



## THERMAL CHARACTERISTICS – DW PACKAGE

| PARAMETER                                                     | TEST CONDITIONS                                                                                                                                                                          | MIN | TYP  | MAX  | UNIT               |
|---------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|------|------|--------------------|
| Junction-to-ambient thermal resistance, $\theta_{JA}^\dagger$ | Low-K board, no air flow                                                                                                                                                                 |     | 96   |      | $^\circ\text{C/W}$ |
|                                                               | High-K board, no air flow                                                                                                                                                                |     | 62.9 |      |                    |
| Junction-to-board thermal resistance, $\theta_{JB}$           | High-K board, no air flow                                                                                                                                                                |     | 39.6 |      |                    |
| Junction-to-case thermal resistance, $\theta_{JC}$            |                                                                                                                                                                                          |     | 29.1 |      |                    |
| Average power dissipation, $P_{(AVG)}$                        | All four channels maximum loading, maximum signaling rate, $R_L = 54\ \Omega$ , input to D is 10 Mbps 50% duty cycle square wave, $V_{CC} = 5.25\text{ V}$ , $T_J = 130^\circ\text{C}$ . |     |      | 1100 | mW                 |
| Ambient free-air temperature, $T_A$                           | JEDEC high-K board model                                                                                                                                                                 | -40 |      | 85   | $^\circ\text{C}$   |
|                                                               | JEDEC high-K board model                                                                                                                                                                 | -40 |      | 64   |                    |
| Thermal shutdown junction temperature, $T_{SD}$               |                                                                                                                                                                                          |     | 165  |      |                    |

<sup>†</sup> See TI application note literature number SZZA003, Package Thermal Characterization Methodologies, for an explanation of this parameter.



## THERMAL CHARACTERISTICS OF IC PACKAGES

$\Theta_{JA}$  (Junction-to-Ambient Thermal Resistance) is defined as the difference in junction temperature to ambient temperature divided by the operating power

$\Theta_{JA}$  is NOT a constant and is a strong function of

- the PCB design (50% variation)
- altitude (20% variation)
- device power (5% variation)

$\Theta_{JA}$  can be used to compare the thermal performance of packages if the specific test conditions are defined and used. Standardized testing includes specification of PCB construction, test chamber volume, sensor locations, and the thermal characteristics of holding fixtures.  $\Theta_{JA}$  is often misused when it is used to calculate junction temperatures for other installations.

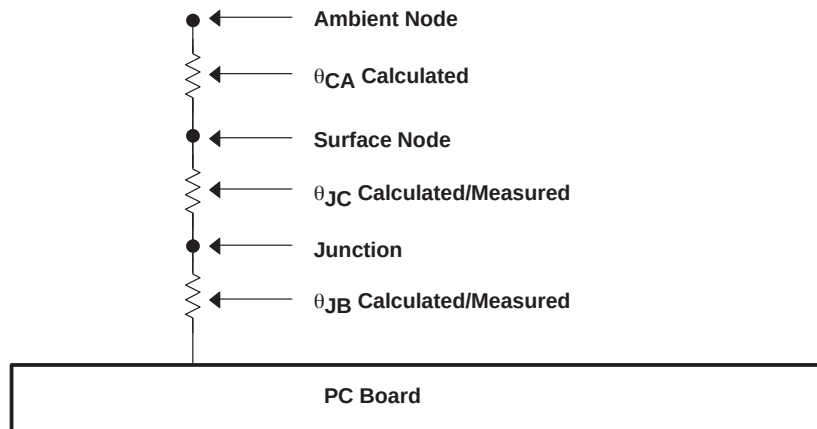
TI uses two test PCBs as defined by JEDEC specifications. The low-k board gives *average* in-use condition thermal performance and consists of a single trace layer 25 mm long and 2-oz thick copper. The high-k board gives *best case* in-use condition and consists of two 1-oz buried power planes with a single trace layer 25 mm long with 2-oz thick copper. A 4% to 50% difference in  $\Theta_{JA}$  can be measured between these two test cards

$\Theta_{JC}$  (Junction-to-Case Thermal Resistance) is defined as difference in junction temperature to case divided by the operating power. It is measured by putting the mounted package up against a copper block cold plate to force heat to flow from die, through the mold compound into the copper block.

$\Theta_{JC}$  is a useful thermal characteristic when a heatsink is applied to package. It is NOT a useful characteristic to predict junction temperature as it provides pessimistic numbers if the case temperature is measured in a non-standard system and junction temperatures are backed out. It can be used with  $\Theta_{JB}$  in 1-dimensional thermal simulation of a package system.

$\Theta_{JB}$  (Junction-to-Board Thermal Resistance) is defined to be the difference in the junction temperature and the PCB temperature at the center of the package (closest to the die) when the PCB is clamped in a cold-plate structure.  $\Theta_{JB}$  is only defined for the high-k test card.

$\Theta_{JB}$  provides an overall thermal resistance between the die and the PCB. It includes a bit of the PCB thermal resistance (especially for BGA's with thermal balls) and can be used for simple 1-dimensional network analysis of package system (see Figure 12).



**Figure 12. Thermal Resistance**

**PACKAGING INFORMATION**

| Orderable Device | Status <sup>(1)</sup> | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <sup>(2)</sup> | Lead/ Ball Finish | MSL Peak Temp <sup>(3)</sup> | Samples (Requires Login) |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|-------------------|------------------------------|--------------------------|
| SN65LBC172DW     | ACTIVE                | SOIC         | DW              | 20   | 25          | Green (RoHS & no Sb/Br) | CU NIPDAU         | Level-1-260C-UNLIM           |                          |
| SN65LBC172DWG4   | ACTIVE                | SOIC         | DW              | 20   | 25          | Green (RoHS & no Sb/Br) | CU NIPDAU         | Level-1-260C-UNLIM           |                          |
| SN65LBC172N      | ACTIVE                | PDIP         | N               | 16   | 25          | Pb-Free (RoHS)          | CU NIPD           | N / A for Pkg Type           |                          |
| SN65LBC172NE4    | ACTIVE                | PDIP         | N               | 16   | 25          | Pb-Free (RoHS)          | CU NIPD           | N / A for Pkg Type           |                          |
| SN75LBC172DW     | ACTIVE                | SOIC         | DW              | 20   | 25          | Green (RoHS & no Sb/Br) | CU NIPDAU         | Level-1-260C-UNLIM           |                          |
| SN75LBC172DWG4   | ACTIVE                | SOIC         | DW              | 20   | 25          | Green (RoHS & no Sb/Br) | CU NIPDAU         | Level-1-260C-UNLIM           |                          |
| SN75LBC172DWR    | ACTIVE                | SOIC         | DW              | 20   | 2000        | Green (RoHS & no Sb/Br) | CU NIPDAU         | Level-1-260C-UNLIM           |                          |
| SN75LBC172DWRG4  | ACTIVE                | SOIC         | DW              | 20   | 2000        | Green (RoHS & no Sb/Br) | CU NIPDAU         | Level-1-260C-UNLIM           |                          |
| SN75LBC172N      | ACTIVE                | PDIP         | N               | 16   | 25          | Pb-Free (RoHS)          | CU NIPD           | N / A for Pkg Type           |                          |
| SN75LBC172NE4    | ACTIVE                | PDIP         | N               | 16   | 25          | Pb-Free (RoHS)          | CU NIPD           | N / A for Pkg Type           |                          |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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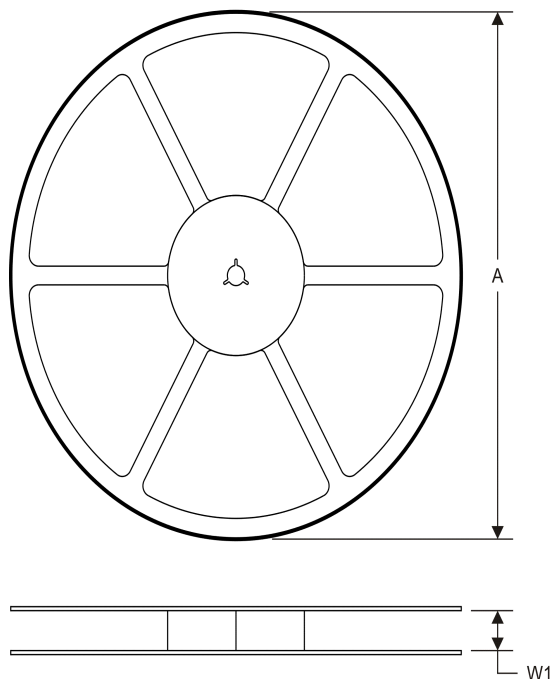
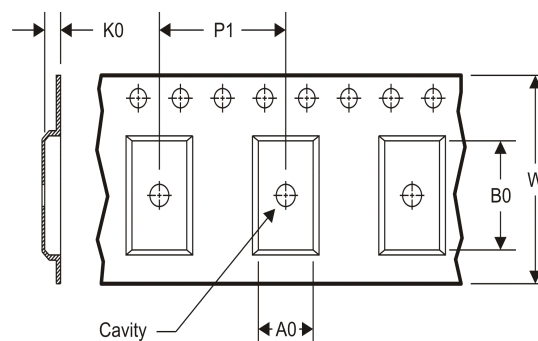
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**OTHER QUALIFIED VERSIONS OF SN75LBC172 :**

- Military: [SN55LBC172](#)

NOTE: Qualified Version Definitions:

- Military - QML certified for Military and Defense Applications

**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

**TAPE DIMENSIONS**


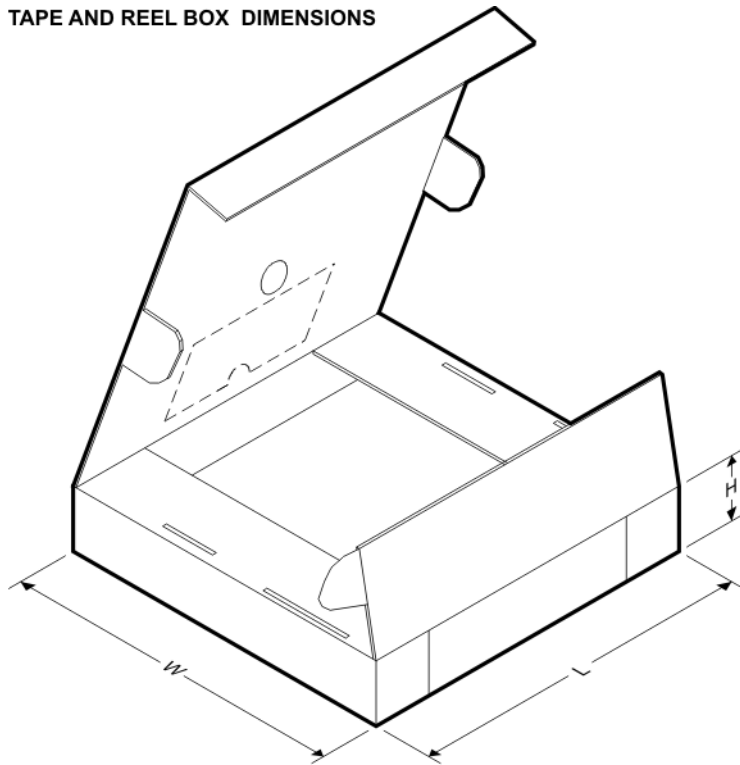
|    |                                                           |
|----|-----------------------------------------------------------|
| A0 | Dimension designed to accommodate the component width     |
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

**TAPE AND REEL INFORMATION**

\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| SN75LBC172DWR | SOIC         | DW              | 20   | 2000 | 330.0              | 24.4               | 10.8    | 13.0    | 2.7     | 12.0    | 24.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



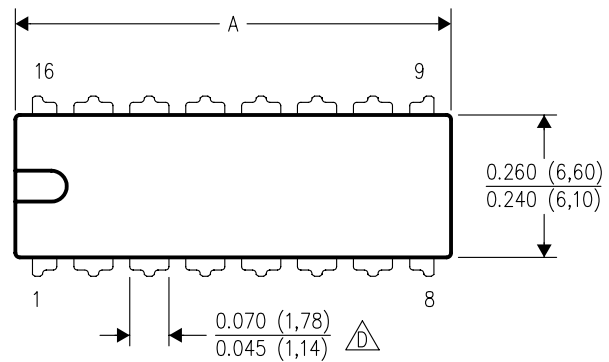
\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN75LBC172DWR | SOIC         | DW              | 20   | 2000 | 367.0       | 367.0      | 45.0        |

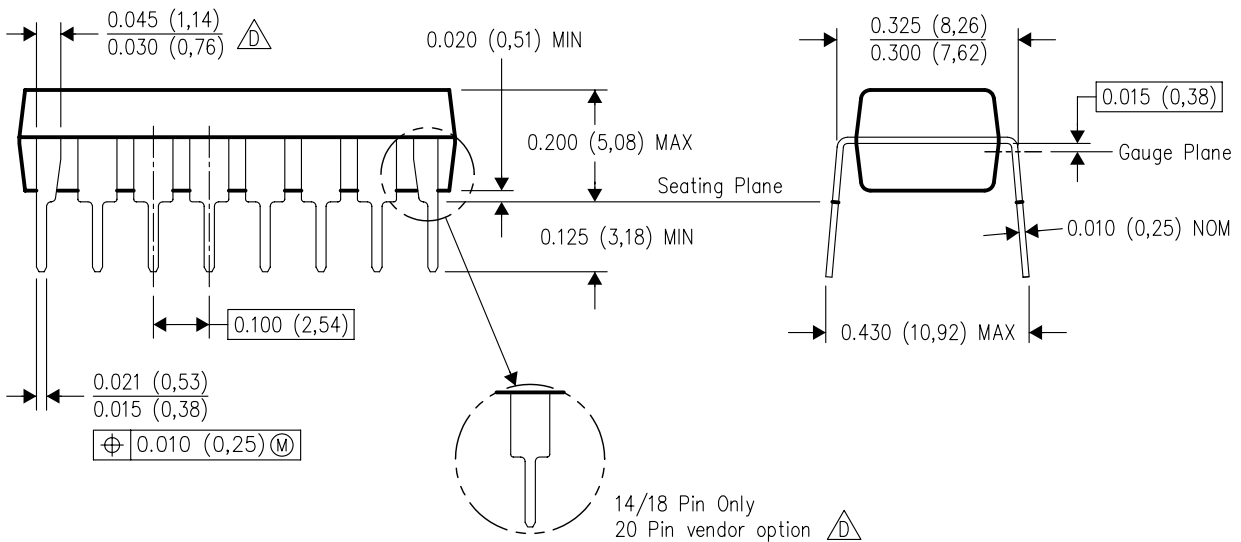
## N (R-PDIP-T\*\*)

16 PINS SHOWN

## PLASTIC DUAL-IN-LINE PACKAGE



| PINS **             | 14               | 16               | 18               | 20               |
|---------------------|------------------|------------------|------------------|------------------|
| DIM                 |                  |                  |                  |                  |
| A MAX               | 0.775<br>(19,69) | 0.775<br>(19,69) | 0.920<br>(23,37) | 1.060<br>(26,92) |
| A MIN               | 0.745<br>(18,92) | 0.745<br>(18,92) | 0.850<br>(21,59) | 0.940<br>(23,88) |
| MS-001<br>VARIATION | AA               | BB               | AC               | AD               |



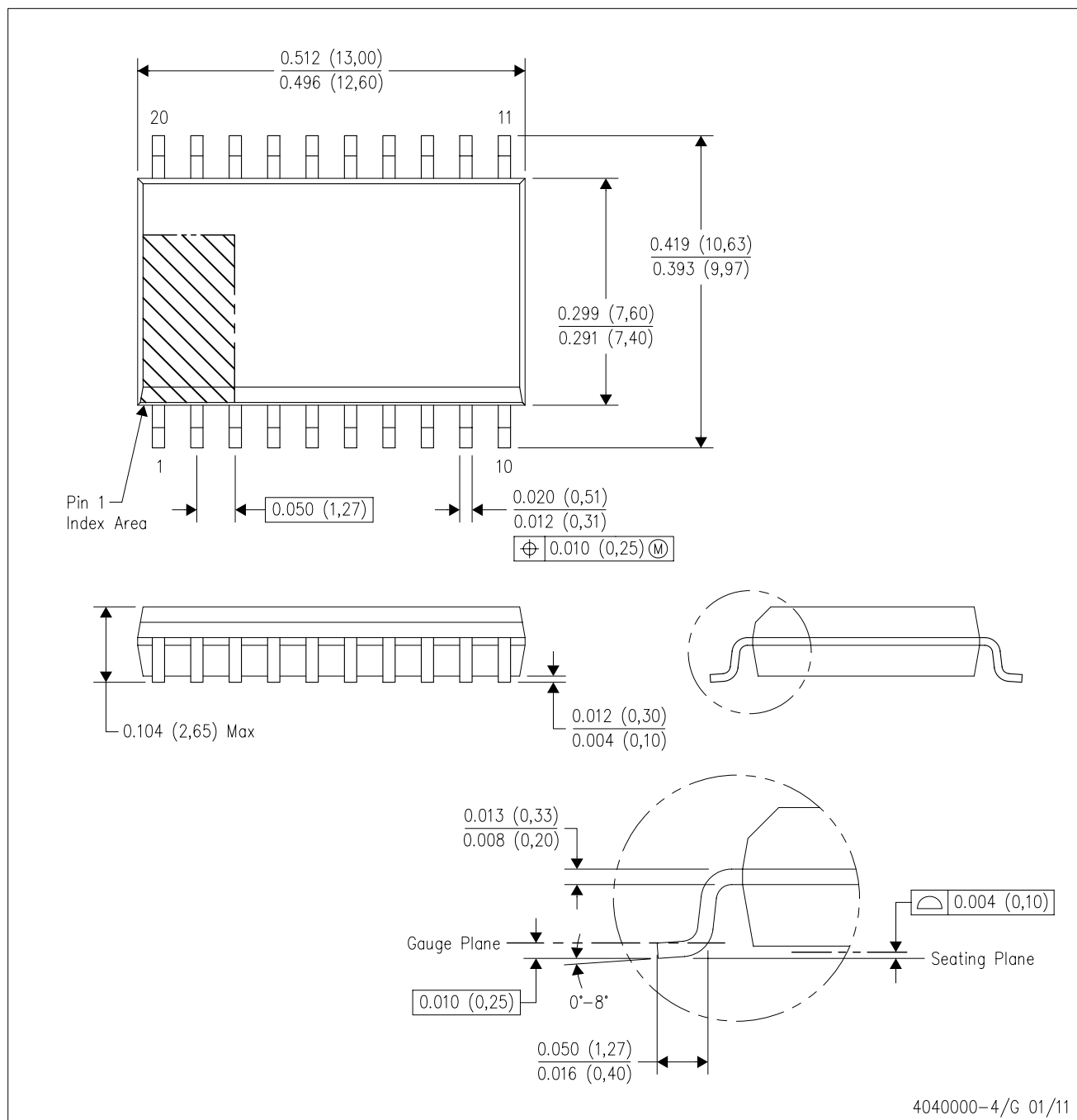
14/18 Pin Only  
20 Pin vendor option

4040049/E 12/2002

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - The 20 pin end lead shoulder width is a vendor option, either half or full width.

DW (R-PDSO-G20)

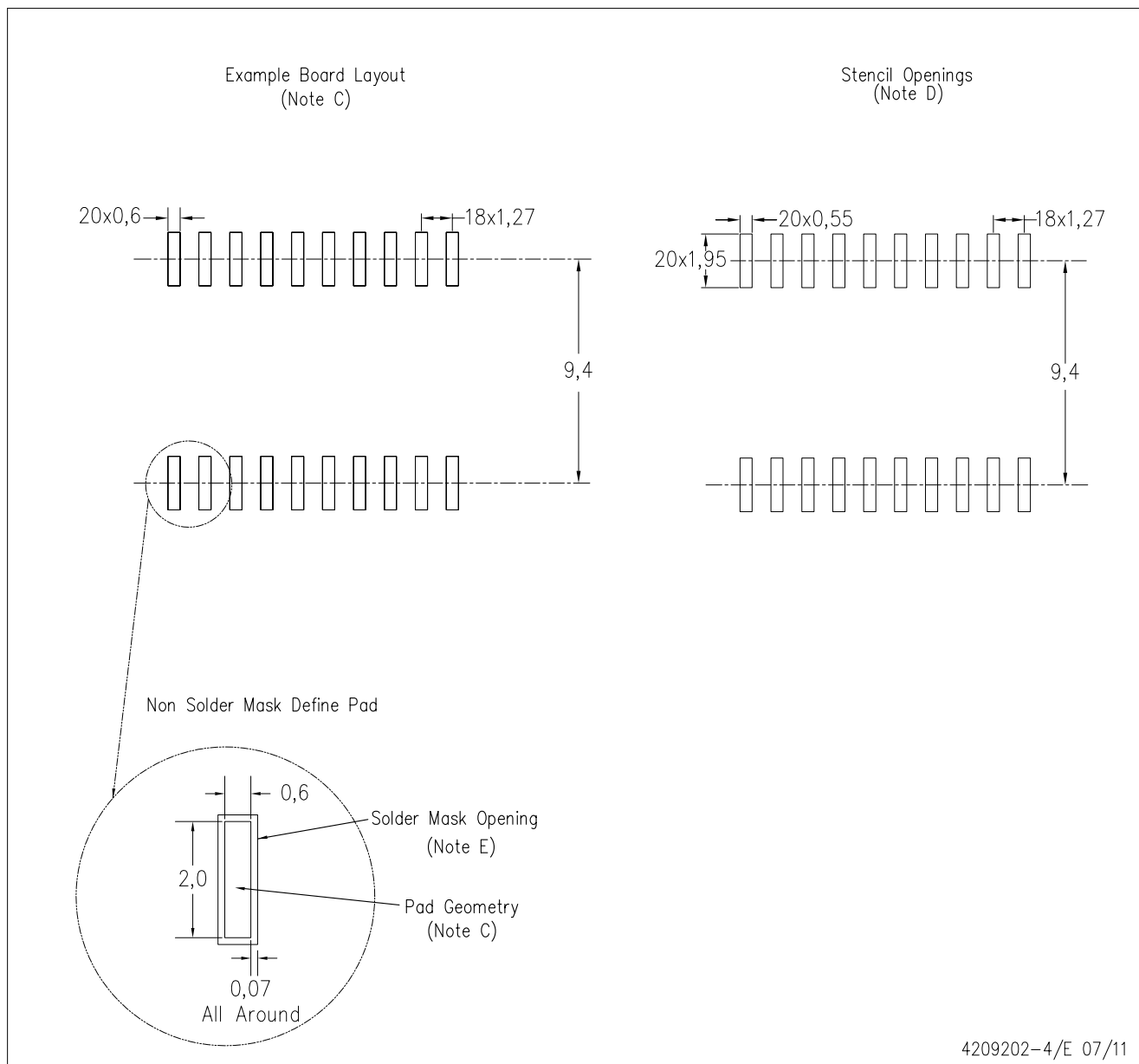
PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - Falls within JEDEC MS-013 variation AC.

DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Refer to IPC7351 for alternate board design.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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| RFID                   | <a href="http://www.ti-rfid.com">www.ti-rfid.com</a>                                 |
| OMAP Mobile Processors | <a href="http://www.ti.com/omap">www.ti.com/omap</a>                                 |
| Wireless Connectivity  | <a href="http://www.ti.com/wirelessconnectivity">www.ti.com/wirelessconnectivity</a> |

### Applications

|                               |                                                                                          |
|-------------------------------|------------------------------------------------------------------------------------------|
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| Consumer Electronics          | <a href="http://www.ti.com/consumer-apps">www.ti.com/consumer-apps</a>                   |
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